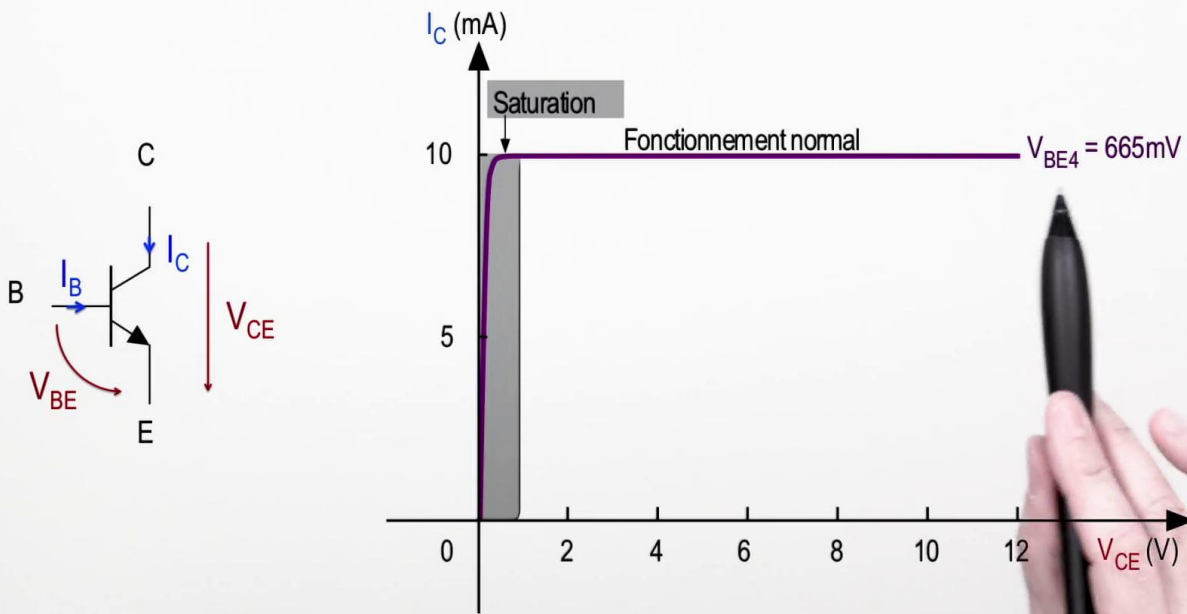




# Caractéristiques du transistor $I_c = f(U_{CE})$



Electronique II

We saw the transistor in its transfer characteristics that is  $V_{be} f(I_c)$ , so the input voltage and the output current. We have seen the relationship between  $I_b$  and  $I_c$  which gave us the  $\beta$  of the transistor. Now we will study the transistor effect, that is, this current source that man wanted to create to make electronic circuits. We will pass on to the output characteristic of a bipolar transistor. If you look at this feature here and you look at what's on the axes, let's come back to this diagram. Here I have  $I_c$  and here I have  $V_{be}$  and I am looking at  $V_{ce}$ . I'd like to see what will happen with the transistor when  $V_{ce}$  will vary. All our attention is on this  $V_{ce}$ , since we have already demonstrated that  $I_c$  is controlled by  $V_{be}$ . We've seen that this current is controlled by this. How this transistor effect is and what are the characteristics that allow us to analyze what will happen to the output? Remember, the output will often be between the collector and transmitter or transmitter or collector, it depends on which side we will connect our charge. This is the  $I_c V_{ce}$  law. But look what I noticed here in the constant voltage I just put a  $V_{be4}$  voltage, I called it 4, it is equal to 665 mV.

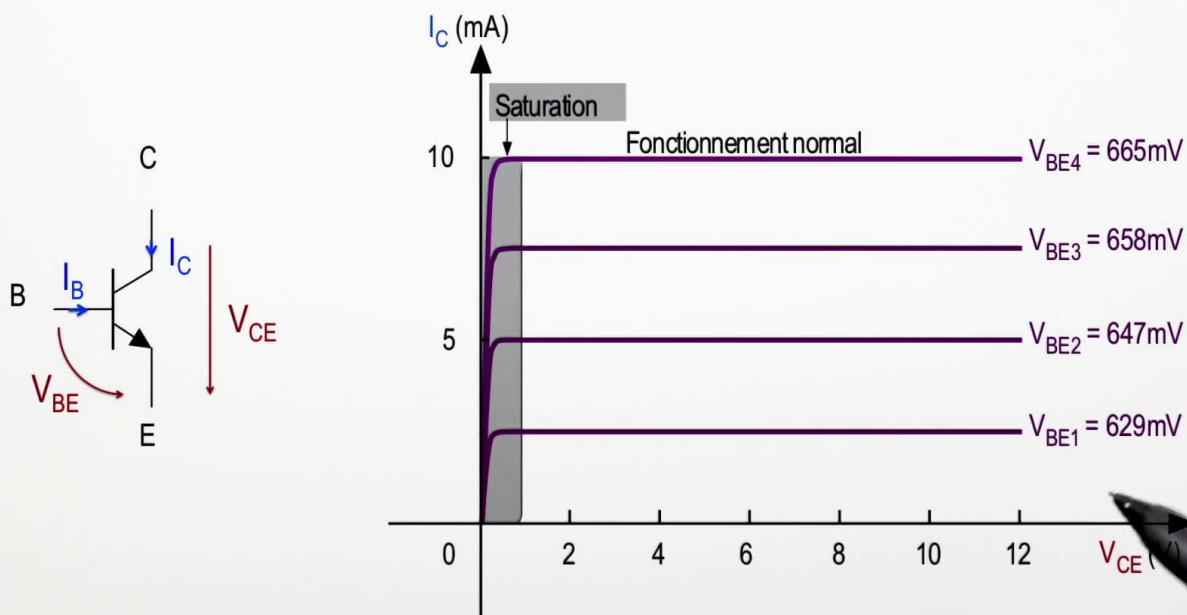
Notes

Summary



0m 04s

# Caractéristiques du transistor $I_c = f(U_{ce})$



Electronique II

So, for a voltage here of the order of magnitude of  $U_j$ , but of course  $U_j$  we said it was the exponential and it is a value taken on the exponential law. When you look here, you see that the current has been absolutely independent of the the voltage variation  $U_{ce}$ . You vary  $U_{ce}$  as you desire. So you vary  $U_{ce}$  throughout this range, you will see that  $I_c$  is not at all affected by what happens. So it is a source of current. The current is fully controlled by it because if you now vary  $V_{be}$ , if suddenly you put another voltage  $V_{be}$ , look what happens. I put a slightly lower voltage and I lowered the current that is controlled by it. This voltage, I lowered it, the current will follow it according to the famous exponential law we had seen. If you keep doing the same thing, you change  $V_{be}$  and you again put a lower voltage. But when I say lower, look at the difference it is always around the same value. Remember that the control of  $I_c V_{be}$  is an exponential law, so we just need a little variation on this  $V_{be}$  so that the current varies exponentially in relation to this and that's what I'm doing. I'm going to lower it again, so I get to a certain value of  $V_{be}$ . Whenever I move this tension here, the current changes with it.

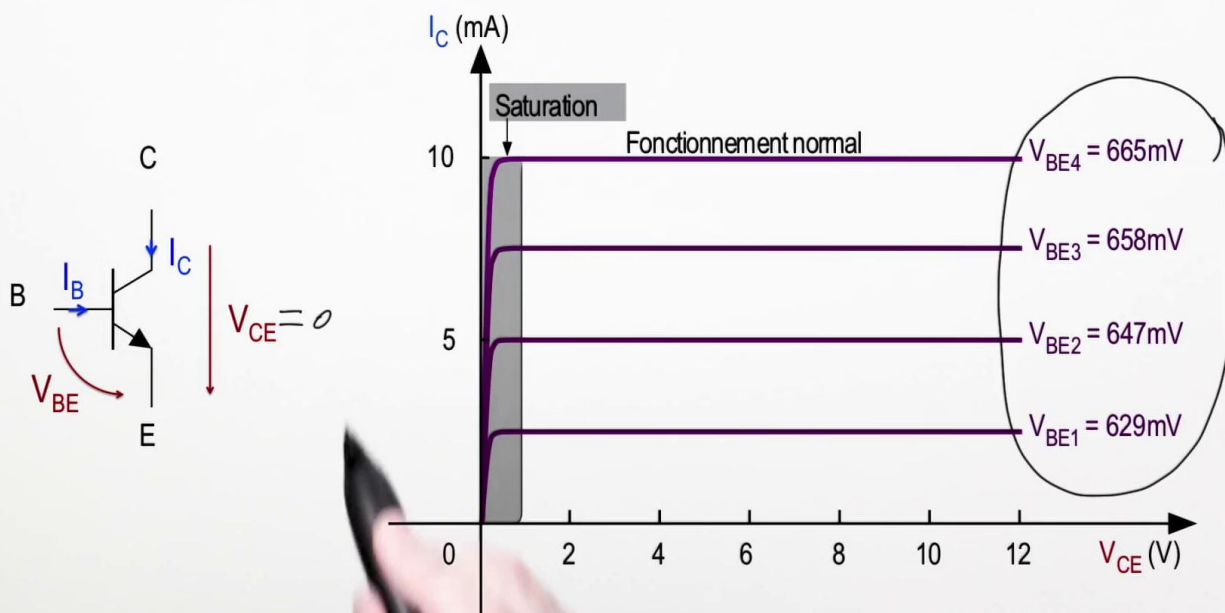
Notes

Summary



1m 44s

# Caractéristiques du transistor $I_C = f(U_{CE})$



Electronique II

So I increase the voltage, I lower the voltage and I have current sources. It's called controlled current sources that will follow the variation in the voltage  $V_{be}$ . I insist on the fact that when you look at the  $V_{be}$  variation, remember that it is controlled by an exponential law, so very little variation here induces a lot of variation on the current here. This is why I have variations between 629 mV to 665 mV which varies the current of something of the order of 2.5 mA to 10 mA. It is this tension that has no effect, but look carefully, when the voltage  $V_{ce}$  gets somewhere in this area called the saturation zone, we will explain it, and especially when  $V_{ce}$  goes to 0 and close to 0, this superb power source and this constant value of the current  $I_C$  is not as constant than we imagine, it starts to fall. When  $V_{ce}$  is equal to 0, in first approximation the transistor enters something we call saturation. And I'd like to emphasize this before moving on to another explanation. It was said that  $V_{ce}$  does not affect the current  $I_C$ . I'm saying if and only if  $V_{ce}$  is equal to 0, this affects. This is simply confined to that condition that we lose the transistor characteristic in current source.

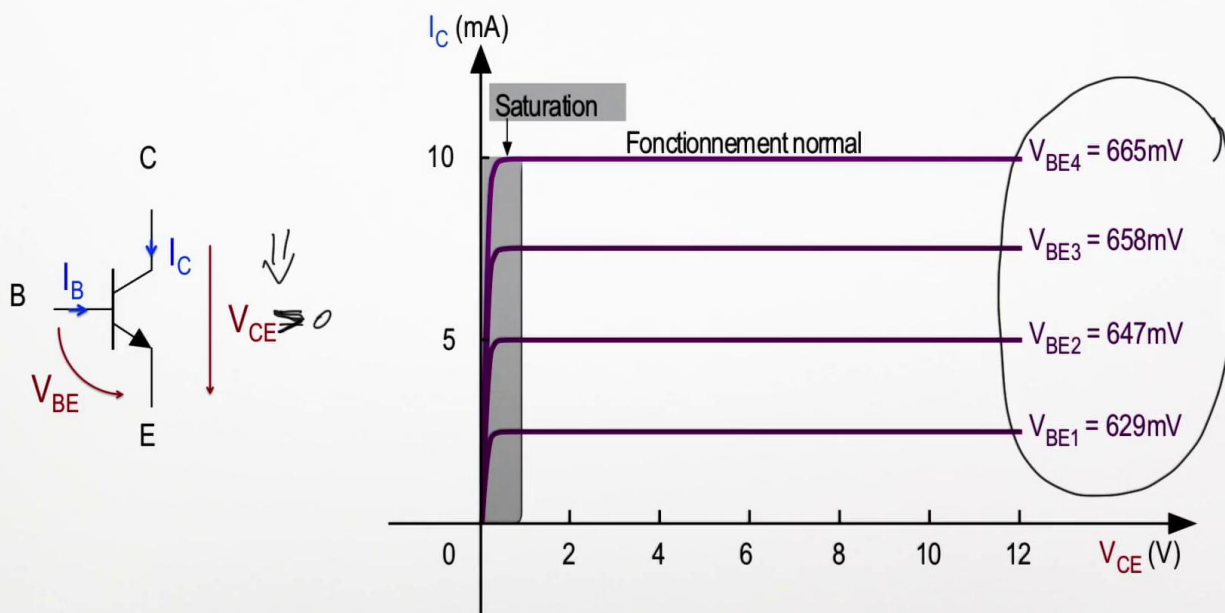
Notes

Summary



3m 29s

# Caractéristiques du transistor $I_c = f(U_{ce})$



Electronique II

The value of current we have is controlled by the  $V_{be}$ . This is the famous electrons tap that allows this transistor as  $V_{ce}$  is not equal to 0 to stay in normal running. I just added an extra word and a second word also, I speak of a transistor that conduct, but when it conducts, it has two states. A state called normal is what will be of interest to us in analog circuits, and a state we call saturation is when the voltage  $U_{ce}$  becomes 0. Please retain these two things and remember that ultimately  $I_c$  controlled by  $V_{be}$  has no longer this law that interests us when  $V_{ce}$  is 0. Who will decide that  $V_{ce}$  is 0? It is you who will decide, it is your circuit. If by chance you put a resistor in which you move the current (at)  $I_c$ , the higher the current (at)  $I_c$  increases, the more voltage drop at the edge of this resistance will increase. So you risk saturating the transistor. This is not a proper transistor characteristic, it's up to you in your circuit to ensure that  $V_{ce}$  is greater than or strictly greater than 0 to ensure that your transistor is in normal operation. It is as if you were saying "I want to use the transistor from here to certain values", that's up to you to decide. But make sure that  $V_{ce}$  does not come here because I do not have this behavior I see here.

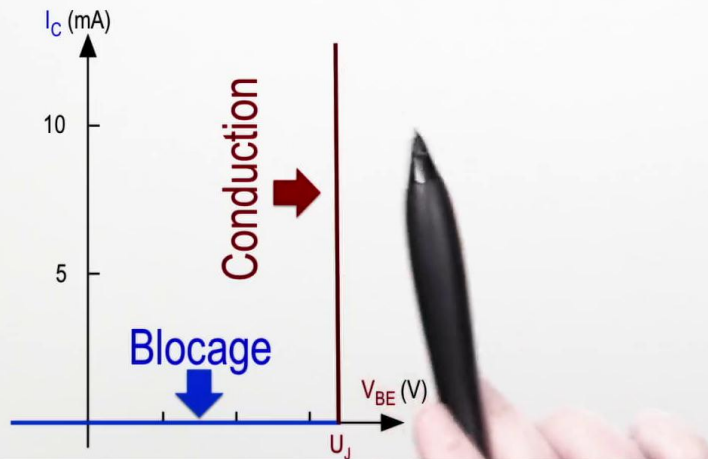
Notes

Summary



5m 10s

- **Modèle linéaire grands signaux (DC):**
  - Jonction BE conduit,  $V_{BE} \approx U_J$
  - Jonction BE Bloquée,  $V_{BE} < U_J$
- **Modèle linéaire petits signaux (AC):**



Electronique II

I'd like to start now to introduce the modeling of what we presented so far. I told you of linear large-signal model, we will call it large-signal. I repeat, we will talk about a DC mode, that is we are in the world of direct current and direct voltage. We will talk of this model and this model will be fully differentiated from this model called linear model small signals. We will talk about AC. The fundamental difference between one and the other, it will help us always to polarize the transistor. This will allow us to use the transistor for amplifying signals and allow linear signals using the transistor. Remember, the transistor can be blocked. And remember that the transistor can be saturated. These two words we selected earlier, blocked and saturated, are the two key words that will guarantee us if the transistor is not blocked or saturated, I can use it and here I'm talking about small signal linear model. But you have the opportunity to better understand this with examples. When I take the linear large-signal model, remember that the base-transmitter junction for the transistor conducts should be in the order of magnitude of EG. So I'll use this model.

Notes

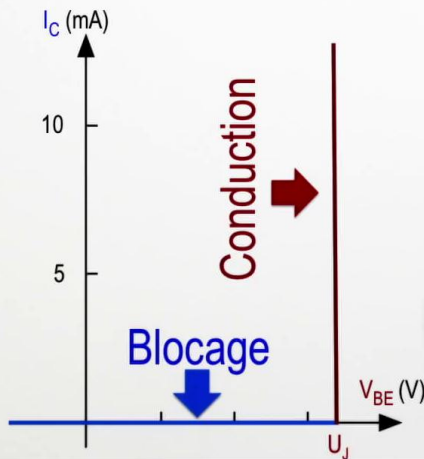
Summary



6m 44s



- Modèle linéaire grands signaux (DC):
  - Jonction BE conduit,  $V_{BE} \approx U_J$
  - Jonction BE Bloquée,  $V_{BE} < U_J$
- Modèle linéaire petits signaux (AC):



Electronique II

Believe me, this is the model you are going to use all the time when you put your transistor in a set-up and you put voltages and direct current before superimposing anything as variable signals we'd like to amplify. We are in a purely DC world and we will use this model, it is of tremendous simplicity. Your voltage, if you can guarantee that  $V_{be}$  is of order of the magnitude of  $U_J$ , know that the transistor will conduct, so know that you will have current in the transistor. What is the value of this current? Nobody knows, you will have to put it in a circuit. But there is one thing, if there is a current in the transistor, you can immediately replace  $V_{be}$  by  $U_J$ . This is an approximation and it is an approximation just because you replaced the exponential by this. I take the transistor and say "If I do not have  $V_{be}$  is equal to  $U_J$ , so I'm in somehow a lower position", know that there is no current flowing in either the transmitter or in the base. It is at the limit, if you are here, and you remove the transistor from the circuit and you will not see anything. It has two operating conditions that give us immediately a voltage that can be used, saying "The transistor conducts."

Notes

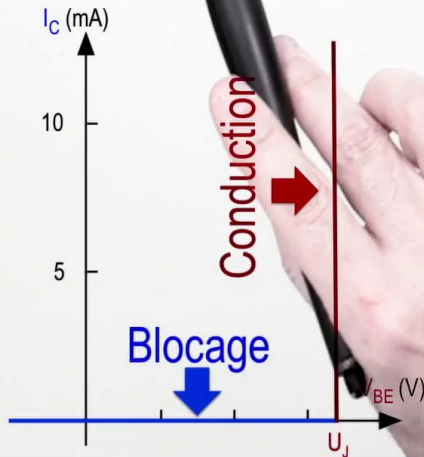
Summary



8m 16s

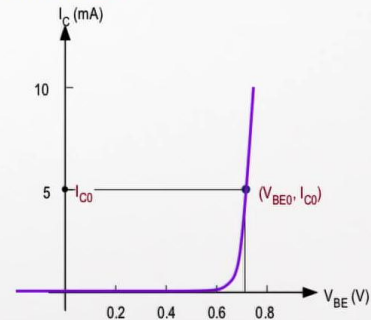
## • Modèle linéaire grands signaux (DC):

- Jonction BE conduit,  $V_{BE} \approx U_j$
- Jonction BE Bloquée,  $V_{BE} < U_j$



## • Modèle linéaire petits signaux (AC):

- Le transistor est en conduction
- Linéarisation autour d'un point de fonctionnement DC



Electronique II

I have observed that there is a current in the collector. So there could be current in the base since both are linearly proportional." At that time, I will say "Vbe is equal to Uj and this curve shows it to me." The law that shows us what is the largest linear model in DC slot comes down to this part of this curve and this part. No current, a non defined current but which exists, but especially when it exists, there is an AUj voltage. I would like to take the small signals linear model. Look what I drew here and look what I drew here. Here, I do not draw this, this I will use just to simplify the calculation and to say Vbe is equal to Uj is all I'll get out of this. I will now move on the real exponential law. I insist on the fact that you will see that the law itself will serve me analytically, but it's rather the derivative of this law that will serve me that the law itself. If you guarantee me that the transistor conducts, so that you are here, and this voltage is equal to this, so you're here. If anyone can verify that Vbe is equal to Uj, of order of magnitude it's 0.6; 0.65; 0.71; all this means that it is of the order of magnitude of the junction voltage.

Notes

Summary

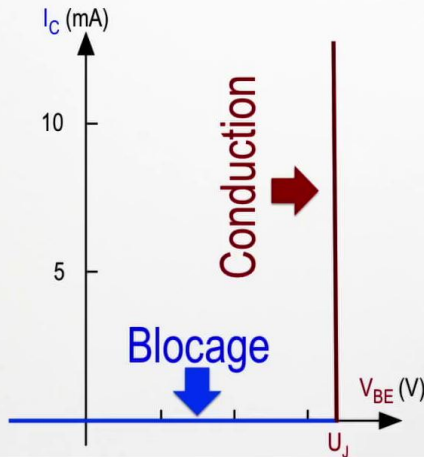


9m 35s



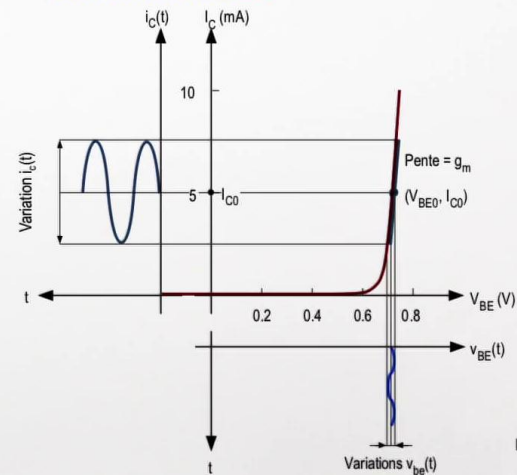
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- Jonction BE conduit,  $V_{BE} \approx U_J$
- Jonction BE Bloquée,  $V_{BE} < U_J$



## • Modèle linéaire petits signaux (AC):

- Le transistor est en conduction
- Linéarisation autour d'un point de fonctionnement DC



Know that your transistor is currently conducting. So you're somewhere here. As it was approximated by a straight line, here I take the real exponential law. There is a current flowing through your transistor and this is the  $I_C$  current for which there is of course a voltage of the order of  $U_J$ . But then if you now superimpose this voltage which is here, which is of course not the latter because it is a rough approximation, if you put that point in the exponential law, you are on an operation point, hence the name operating point. There is a continuous current and a voltage  $V_{be0}$  of a given value. Know that your transistor is on this law or on this exponential slope of the relationship  $I_C$   $V_{be}$ . What is happening here ? What will happen when you take this law and this explanation I just gave and you take the point that we just saw a moment ago with a direct current, a direct voltage. And you come here, and superimpose a small variation, we call it increase. I remind you when we looked at the output characteristic, we were talking of mV there, so if you take a few variations of  $V_{be}$  few mV, you will see a change in the current following it.

Notes

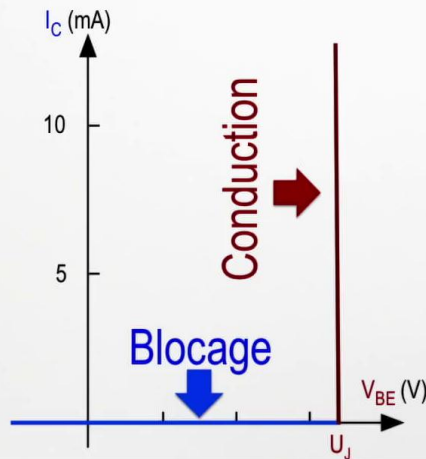
Summary



# Modèles linéaires

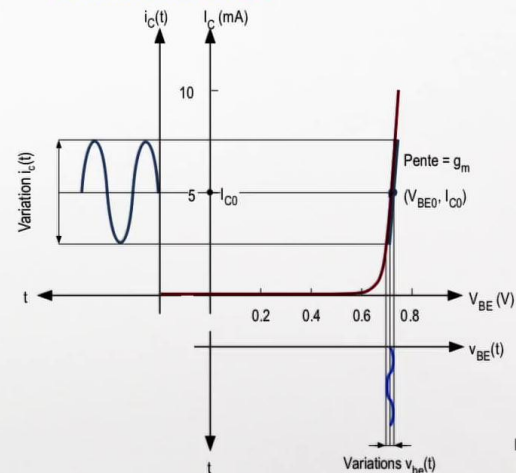
## • Modèle linéaire grands signaux (DC):

- Jonction BE conduit,  $V_{BE} \approx U_J$
- Jonction BE Bloquée,  $V_{BE} < U_J$



## • Modèle linéaire petits signaux (AC):

- Le transistor est en conduction
- Linéarisation autour d'un point de fonctionnement DC



Electronique II

Remember that  $V_{be}$  is the tap that controls the current flowing, and we fixed a point and then started moving around the fixed point in order to control a current, and that current, will give us a current in the collector which is in the image of this voltage. This is the transistor: it took  $V_{be}$ , it transformed it into a current  $I_c$ . And if this law and this are linear, you have found, what we will call trans-conductance later on, that is, the approximation of the exponential law around these two points we extracted from these that we applied to this curve one. And we take another point and if you vary this voltage then between base-emitter, it will control you the current in the collector. And the one that say that I have current in the collector of a given value, you just need to put this current in a resistor, it becomes a voltage. So I converted a  $V_{be}$  voltage into a current. If I put this current, which is the image of  $V_{be}$ , I find a voltage which is the image of this current. And that is done through the resistor. So what I'd like you to remember of this curve here: when I speak of an AC model is that I have surely already used the DC model.

Notes

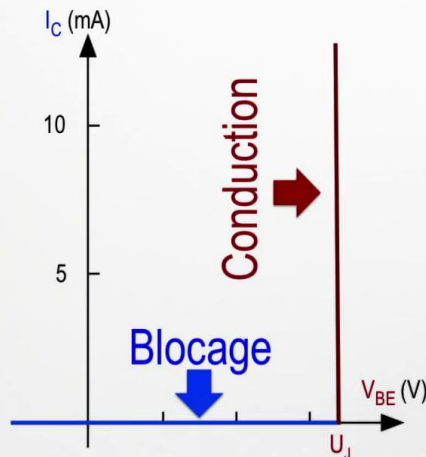
Summary



12m 27s

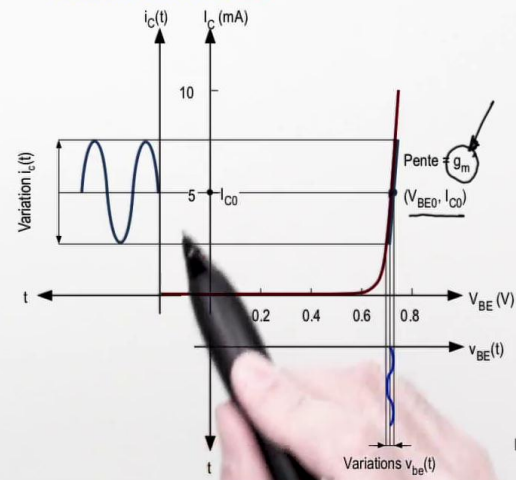
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- Jonction BE conduit,  $V_{BE} \approx U_J$
- Jonction BE Bloquée,  $V_{BE} < U_J$



## • Modèle linéaire petits signaux (AC):

- Le transistor est en conduction
- Linéarisation autour d'un point de fonctionnement DC



Electronique II

And when I used the DC model, I applied an approximation, but I do not know the exact value I applied. But when I apply this and I do a DC calculation, it will allow me to know the values that will come out here. And values from here will allow me to make the approximation that here, I'm on the exact law. But from this exact law, what should I take? Should I take this whole curve? Not at all ! I could just accept, approximating a small portion of this curve, which is tangent on this point and I do the approximation that the slope of the tangent I'll call the  $G_m$  is the conversion of  $V_{be}$  into a current, we will call the transconductance, that means I'm in AC and I just have to know the value of  $G_m$  and that will be a goal in itself, on how to extract the  $G_m$  of a transistor, so what is the slope of the tangent that we see here on this feature and once we have it, you will see the door of the use of linear models is wide open, it will allow us to consider that any change in voltage is transformed into a variation of current. And that this current could change if one wishes or keep it in current, or put it in a resistor and convert it into voltage.

Notes

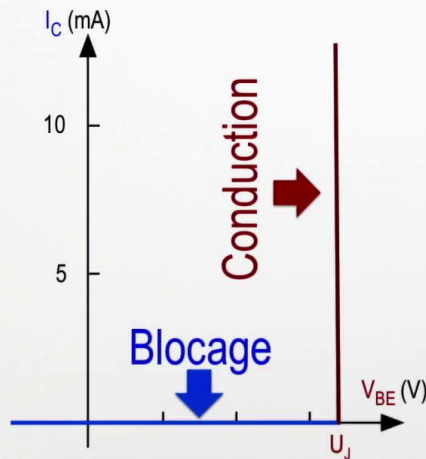
Summary



13m 48s

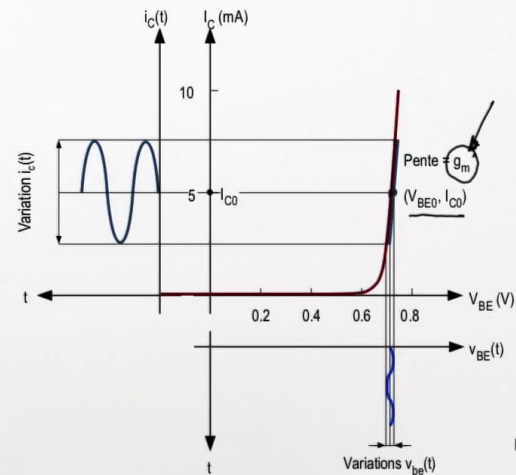
## • Modèle linéaire grands signaux (DC):

- Jonction BE conduit,  $V_{BE} \approx U_J$
- Jonction BE Bloquée,  $V_{BE} < U_J$



## • Modèle linéaire petits signaux (AC):

- Le transistor est en conduction
- Linéarisation autour d'un point de fonctionnement DC



Electronique II

We would have made with that, a voltage amplifier: I will take a base-transmitter variation and I'll watch its image in current with the output current and I will put the output current in a resistor so I convert it into an output voltage and it will be the first amp that we will study later.

Notes

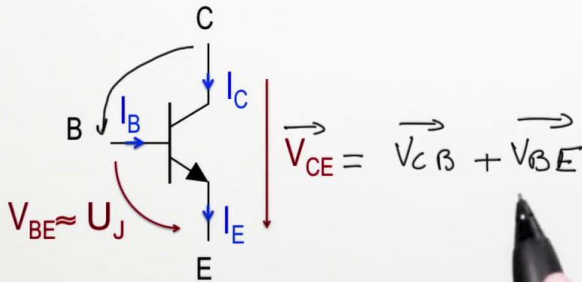
Summary



## • Fonctionnement normal:

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$

## • Fonctionnement saturé



Electronique II

I would like to now take these different things and use the transistor in the normal world. I would also repeat that we said when a transistor conducts, there is a risk of being saturated, that is when  $U_C$  is zero. So I would like to differentiate the two: the transistor conducts as soon as I said that the transistor is conducting, I can immediately say, when a transistor conducts, the base-transmitter junction is of the order of magnitude of  $U_J$ . That, I think everyone now understands that the linear model by segment in which I made this vast abstraction, that there is no exponential, and I have two parts which describe the exponential. Here, when I am told that there is an  $I_C$  current, I will tell you, "yes the  $V_{be}$  voltage is of the order of  $U_J$ . What will happen with this junction here? So, the transistor, it has: collector, base, emitter. I'll write vectorially what happens with  $V_{ce}$  I will write:  $V_{ce} = V_{be} + V_{cb}$ . So these three vectors, it is a vector addition.  $V_{ce}$  is from here to here,  $V_{cb}$  is from here to here. So this vector is equal to the sum of this plus this and this is what I noted here. Knowing that, I just said: "When the transistor will conduct, I have all the time, in the order of magnitude of  $j$ ." So that, I'm not going to change it.

Notes

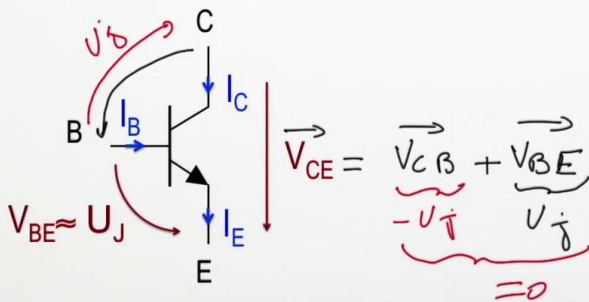
Summary



## • Fonctionnement normal:

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$

## • Fonctionnement saturé



Electronique II

That's going to remain like that. So, what's up with  $V_{cb}$ ?  $V_{cb}$  is less than  $U_J$ , why? The transistor is in normal mode when the voltage from here to here is positive in all time. So if I put my two fingers there, the potential there is above the potential here. This potential is then fixed. So the difference between this and this, it must be positive in that sense. So that's a positive  $V_{cb}$  junction therefore,  $V_{bc}$ , it must be negative and less than  $U_J$ , once the junction begins to reverse, therefore, when the junction begins to be positive in that sense, it can not go beyond a voltage  $U_J$ , why? Because I'm having a PN junction here, as a diode, a PN junction here as a diode. And a diode, it also imposes a voltage  $U_J$  and  $U_J$ . So we take in first order, if this equals this, therefore,  $U_{ce}$  will be zero. So if this equal to  $-U_J$ , remember that this is  $V_{cb}$ , so  $V_{bc}$  is equal  $U_J$ , so  $V_{cb}$  equal to  $-U_J$ , both things will be zero and there, we will find ourselves in the saturated mode. So to ensure that my transistor is fully in the normal mode, I must at all costs ensure that  $V_{be}$  equals to  $U_J$  and  $V_{bc}$  less than  $U_J$ , which induces that  $V_{ce}$  is greater than zero, then it is a positive voltage.

Notes

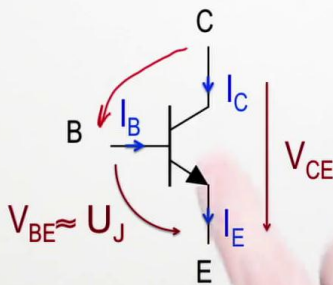
Summary





## • Fonctionnement normal:

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$
- $I_C = \beta I_B$  et  $I_E = I_B + I_C = I_B + \beta I_B = I_B(1 + \beta) \approx I_C$



## • Fonctionnement saturé

Electronique II

So it's sure that the collector potential can decrease below the base potential and can approach zero and at that moment, this junction becomes positive in the other direction and my transistor will be saturated. At that time and only for this mode of operation, I can say that the current  $I_C$  is linearly proportional to  $\beta$ . And the current  $I_E$ , it's the two currents entering my transistor, they are summed and come out by the transmitter. So  $I_E = I_B + I_C$ . So if you change the  $I_C$ , here by  $\beta$  times  $I_B$ , you can write it like this: you have a current  $I_E$  which is equal to  $I_B$  which multiplies  $1 + \beta$ , the  $\beta$ , we said, is something quite large, that is of the order of 100, 200, 300 + 1. So, the 1, I can overlook it and I end up with the current  $I_E$  is almost equal to  $I_C$ . This is an approximation that makes sense, this current here, it is so small compared to this, this one, it is 200 to 300 times higher, which makes  $I_E$  approximately equal to the current  $I_C$ . And all that under normal condition because we were able to ensure that the  $V_{CB}$  junction is positive in this direction and that  $V_{CE}$  remains at that time, strictly positive. So the tension from here to here is all the time positive.

Notes

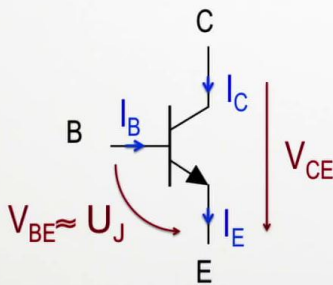
Summary



19m 00s

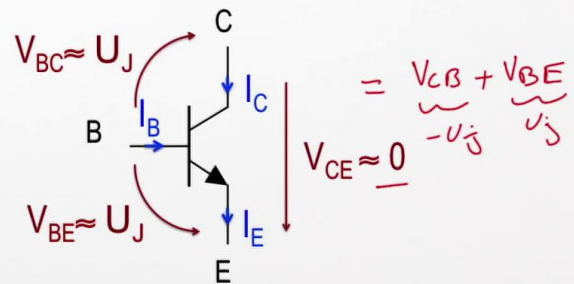
## • Fonctionnement normal:

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$
- $I_C = \beta I_B$  et  $I_E = I_B + I_C = I_B + \beta I_B = I_B(1 + \beta) \approx I_C$



## • Fonctionnement saturé

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC conduit:  $V_{BC} = U_J$  ou  $V_{CE} \approx 0$



Electronique II

Now we will see what will happen with the transistor when it is saturated. Here is what happens with a saturated transistor, this line and this line are the same. The transistor conducts, in both cases, the transistor conducts current. So when it conducts current, we saw that  $V_{be}$  is automatically equal to  $U_J$ . And then there is a mistake, "S" has no place here. So here you have the  $U_{BE}$  is equal to  $U_J$ . But we have seen that, if you take  $V_{ce}$  which is equal to  $V_{cb} + V_{be}$  and you put here  $U_J$  and you put here  $-U_J$ , this voltage is then equal to zero. If this is zero, that is to say, from here to there, I have a voltage where my transistor starts to conduct, finally rather, this junction has a positive voltage in this direction and this junction has a positive voltage in this direction,  $V_{ce}$  is zero and there is the condition for which your transistor is saturated. So, what happens with a saturated transistor? A saturated transistor, you've violated this law. This law is no longer correct. You can't talk no more about the relationship between base current and collector current, on one side and in the output characteristic, you can no longer talk of a current source.

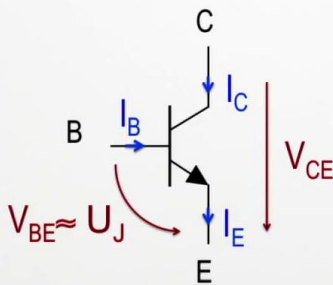
Notes

Summary



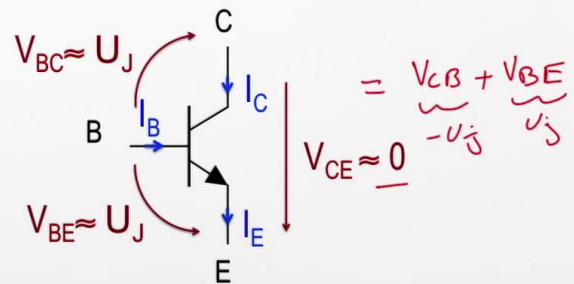
## • Fonctionnement normal:

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- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$
- $I_C = \beta I_B$  et  $I_E = I_B + I_C = I_B + \beta I_B = I_B(1 + \beta) \approx I_C$



## • Fonctionnement saturé

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC conduit:  $V_{BC} = U_J$  ou  $V_{CE} \approx 0$



Electronique II

So this transistor, here, the base-emitter voltage controls the collector. Here, the base-emitter voltage won't control no more the collector current when  $V_{ce}$  equals zero and we can't talk of a transistor which could be used in the analog circuit. You will see it is a transistor that could be used in a digital circuit. So I would like us to make the difference between the two and later we will see that saturating a transistor is connected to the circuits, it has no effect on the transistor itself, this is not related to its characteristics, that is linked to the circuit in which we have placed it at a given time where the current is increased in a way that the voltage  $V_{ce}$  will become zero and at that moment, we can not talk of this no more. We must, at that moment say that  $I_C$  is different from  $\beta$  times  $I_B$  and here we talk of a saturation current and we say the saturation current in the base will be, of course, greater to this law we found here  $\beta$  times  $I_B$  or  $I_C$  equal  $\beta$  times  $I_B$ , this current can be increased and there is nothing that will prevent it if you do not brake it with strokes of resistor.

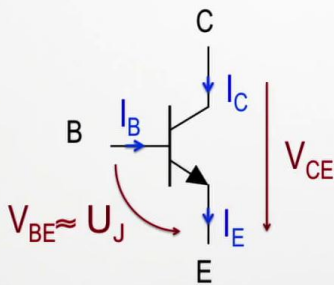
Notes

Summary



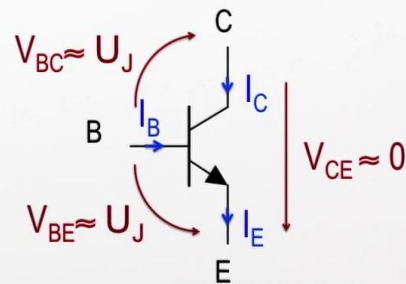
## • Fonctionnement normal:

- Jonction BE conduit:  $V_{BE} \approx U_J$
- Jonction BC bloquée:  $V_{BC} < U_J$  ou  $V_{CE} > 0$
- $I_C = \beta I_B$  et  $I_E = I_B + I_C = I_B + \beta I_B = I_B(1+\beta) \approx I_C$



## • Fonctionnement saturé

- Jonction BE conduit:  $V_{BE} = U_J$
- Jonction BC conduit:  $V_{BC} = U_J$  ou  $V_{CE} \approx 0$
- $I_C \neq \beta I_B$  avec  $I_{Bsat} > I_{Csat}/\beta$



Electronique II

So, I think we analyzed what's happening with the transistor when it conducts and when it is in the normal mode and in the saturated mode, and on the left we can use the transistor in a linear set-up it behaves as a current source. On the right, it will depend on what we put as limitations, but it is a transistor that is no longer used in an analog circuit.

Notes

Summary

